

BC63916 NPN Epitaxial Silicon Transistor

Features

· Switching and Amplifier Applications



Ordering Information

| Part Number | Top Mark | Package | Packing Method |
|--------------|----------|----------|----------------|
| BC63916-D74Z | BC639-16 | TO-92 3L | Ammo |
| BC63916-D27Z | BC639-16 | TO-92 3L | Tape and Reel |

Absolute Maximum Ratings(1)

Stresses exceeding the absolute maximum ratings may damage the device. The device may not function or be operable above the recommended operating conditions and stressing the parts to these levels is not recommended. In addition, extended exposure to stresses above the recommended operating conditions may affect device reliability. The absolute maximum ratings are stress ratings only. Values are at $T_A = 25^{\circ}C$ unless otherwise noted.

| Symbol | Parameter | Value | Unit |
|-----------------------------------|---|------------|------|
| V _{CER} | Collector-Emitter Voltage at R_{BE} = 1 $k\Omega$ | 100 | V |
| V _{CES} | Collector-Emitter Voltage | 100 | V |
| V _{CEO} | Collector-Emitter Voltage | 80 | V |
| V _{EBO} | Emitter-Base Voltage | 5 | V |
| I _C | Collector Current | 1 | Α |
| T _J , T _{STG} | Operating and Storage Junction Temperature Range | -55 to 150 | °C |

Note:

1. Pulse test: pulse width \leq 300 μ s, duty cycle \leq 2.0%.

Thermal Characteristics(2)

Values are at T_A = 25°C unless otherwise noted.

| Symbol | Parameter | Value | Unit |
|-----------------|---|-------|-------|
| l Pn | Power Dissipation | 830 | mW |
| | Derate Above T _A = 25°C | 6.6 | mW/°C |
| $R_{\theta JA}$ | Thermal Resistance, Junction to Ambient | 150 | °C/W |

Note:

2. PCB size: FR-4, 76 mm x 114 mm x 1.57 mm (3.0 inch x 4.5 inch x 0.062 inch) with minimum land pattern size.

Electrical Characteristics

Values are at $T_A = 25^{\circ}C$ unless otherwise noted.

| Symbol | Parameter | Conditions | Min. | Тур. | Max. | Unit |
|-----------------------|--------------------------------------|--|------|------|------|------|
| BV _{CBO} | Collector-Base Breakdown Voltage | $I_C = 100 \mu A, I_E = 0$ | 100 | | | V |
| BV_{CEO} | Collector-Emitter Breakdown Voltage | $I_C = 10 \text{ mA}, I_B = 0$ | 80 | | | V |
| BV _{EBO} | Emitter-Base Breakdown Voltage | $I_E = 10 \mu A, I_C = 0$ | 5.0 | | | V |
| I _{CBO} | Collector Cut-Off Current | $V_{CB} = 30 \text{ V}, I_{E} = 0$ | | | 100 | nA |
| I _{EBO} | Emitter Cut-Off Current | $V_{EB} = 5 \text{ V}, I_{C} = 0$ | | | 10 | μΑ |
| h _{FE} 1 | | $V_{CE} = 2 \text{ V}, I_{C} = 5 \text{ mA}$ | 25 | | | |
| h _{FE} 2 | DC Current Gain | V _{CE} = 2 V, I _C = 150 mA | 100 | | 250 | |
| h _{FE} 3 | | V _{CE} = 2 V, I _C = 500 mA | 25 | | | |
| V _{CE} (sat) | Collector-Emitter Saturation Voltage | I _C = 500 mA, I _B = 50 mA | | | 0.5 | V |
| V _{BE} (on) | Base-Emitter On Voltage | V _{CE} = 2 V, I _C = 500 mA | | | 1 | V |
| f _T | Current Gain Bandwidth Product | $V_{CE} = 5 \text{ V}, I_{C} = 10 \text{ mA},$ f = 50 MHz | | 100 | | MHz |

Typical Performance Characteristics

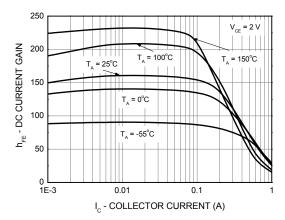


Figure 1. DC Current Gain

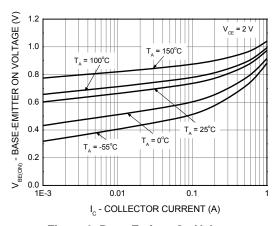


Figure 2. Base-Emitter On Voltage

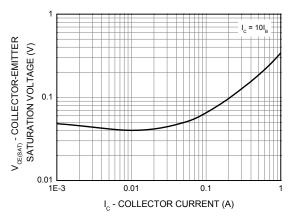


Figure 3. Collector-Emitter Saturation Voltage

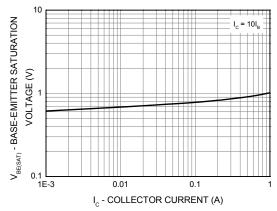
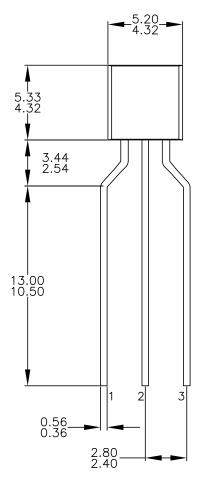
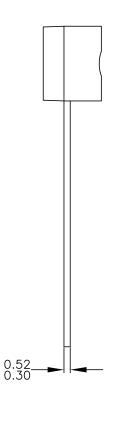
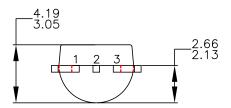


Figure 4. Base-Emitter Saturation Voltage

Physical Dimensions







NOTES: UNLESS OTHERWISE SPECIFIED

- DRAWING CONFORMS TO JEDEC MS-013, VARIATION AC.
 ALL DIMENSIONS ARE IN MILLIMETERS.
 DRAWING CONFORMS TO ASME Y14.5M-2009.
 DRAWING FILENAME: MKT-ZA03FREV3.
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Figure 5. 3-Lead, TO-92, Molded, 0.2 In Line Spacing Lead Form

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